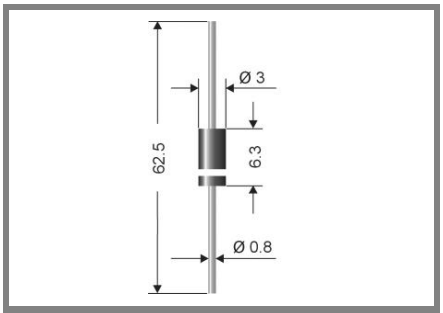
1N 5817...1N 5819



Axial lead diode

Schottky barrier rectifiers diodes

1N 5817...1N 5819

Forward Current: 1 A

Reverse Voltage: 20 to 40 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case DO-15 / DO-204AC
- Weight approx.: 0,4 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 4000 pieces per ammo

1) Valid, if leads are kept at ambient temperature at a distance of 10 mm from case
2) I_F = 3 A, T_j = 25 °C
3) T_A = 25 °C

Type	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Max. reverse recovery time I_F = - A, I_R = - A, I_{RR} = - A, t_{rr} ns	Max. forward voltage V_F 2)
1N 5817	20	20	-	0,750
1N 5818	30	30	-	0,875
1N 5819	40	40	-	0,900

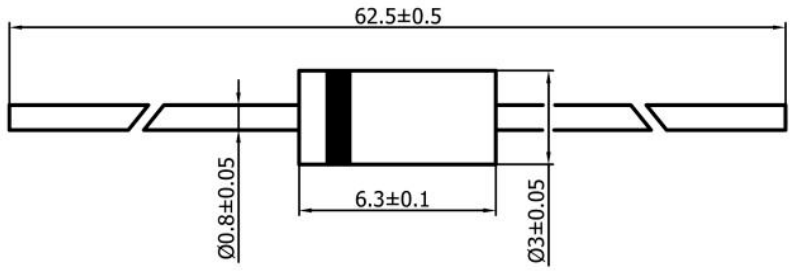
Absolute Maximum Ratings Tc = 25 °C, unless otherwise specified

Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, T_A = 50 °C 1)	1	A
I_{FRM}	Repetitive peak forward current f > 15 Hz 1)	10	A
I_{FSM}	Peak forward surge current 50 Hz half sinus-wave 3)	40	A
i²t	Rating for fusing, t < 10 ms 3)	8	A²s
R_{thA}	Max. thermal resistance junction to ambient 1)	45	K/W
R_{thT}	Max. thermal resistance junction to terminals 1)	15	K/W
T_j	Operating junction temperature	-50...+150	°C
T_s	Storage temperature	-50...+175	°C

Characteristics Tc = 25 °C, unless otherwise specified

Symbol	Conditions	Values	Units
I_R	Maximum leakage current, T_j = 25 °C; $V_R = V_{RRM}$	<1	mA
	T_j = 100 °C; $V_R = V_{RRM}$	<10	mA
C_J	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge (U_R = V; I_F = A; dI_F/dt = A/ms)	-	µC
E_{RSM}	Non repetitive peak reverse avalanche energy (I_R = mA; T_j = °C; inductive load switched off)	-	mJ

Dimensions in mm



case: DO-15 / DO-204AC

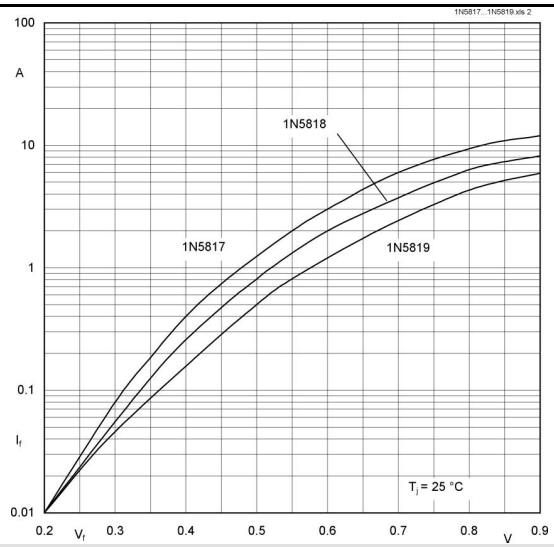


Fig. 1 Forward characteristic (typical values)

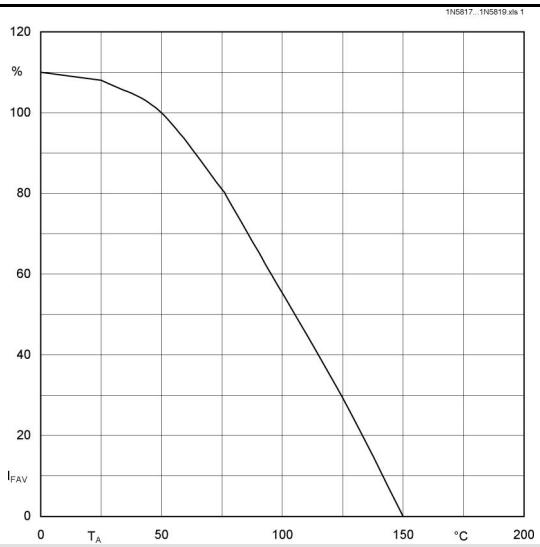


Fig. 2 Rated forward current vs. ambient temperature [1])

